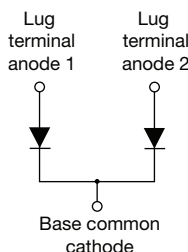


# HEXFRED® Ultrafast Soft Recovery Diode, 320 A



TO-244



## FEATURES

- Very low  $Q_{rr}$  and  $t_{rr}$
- UL approved file E222165 
- Designed and qualified for industrial level
- Material categorization:  
For definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


RoHS  
COMPLIANT

## BENEFITS

- Reduced RFI and EMI
- Reduced snubbing

## DESCRIPTION

HEXFRED® diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems. An extensive characterization of the recovery behavior for different values of current, temperature and  $di_F/dt$  simplifies the calculations of losses in the operating conditions. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for power converters, motors drives and other applications where switching losses are significant portion of the total losses.

| PRODUCT SUMMARY      |                           |
|----------------------|---------------------------|
| $I_{F(AV)}$          | 320 A                     |
| $V_R$                | 400 V                     |
| $I_{F(DC)}$ at $T_C$ | 255 A at 85 °C            |
| Package              | TO-244 (TO-244AB)         |
| Circuit              | Two diodes common cathode |

| ABSOLUTE MAXIMUM RATINGS                         |                |                                                                    |            |       |
|--------------------------------------------------|----------------|--------------------------------------------------------------------|------------|-------|
| PARAMETER                                        | SYMBOL         | TEST CONDITIONS                                                    | MAX.       | UNITS |
| Cathode to anode voltage                         | $V_R$          |                                                                    | 400        | V     |
| Continuous forward current                       | $I_F$          | $T_C = 25\text{ °C}$                                               | 420        | A     |
|                                                  |                | $T_C = 85\text{ °C}$                                               | 255        |       |
|                                                  |                | $T_C = 115\text{ °C}$                                              | 160        |       |
| Single pulse forward current                     | $I_{FSM}$      | Limited by junction temperature                                    | 1200       |       |
| Non-repetitive avalanche energy                  | $E_{AS}$       | $L = 100\text{ }\mu\text{H}$ , duty cycle limited by maximum $T_J$ | 1.4        | mJ    |
| Maximum power dissipation                        | $P_D$          | $T_C = 25\text{ °C}$                                               | 625        | W     |
|                                                  |                | $T_C = 100\text{ °C}$                                              | 250        |       |
| Operating junction and storage temperature range | $T_J, T_{Stg}$ |                                                                    | -55 to 150 | °C    |

| ELECTRICAL SPECIFICATIONS ( $T_J = 25\text{ °C}$ unless otherwise specified) |          |                                             |            |      |      |       |
|------------------------------------------------------------------------------|----------|---------------------------------------------|------------|------|------|-------|
| PARAMETER                                                                    | SYMBOL   | TEST CONDITIONS                             | MIN.       | TYP. | MAX. | UNITS |
| Cathode to anode breakdown voltage                                           | $V_{BR}$ | $I_R = 100\text{ }\mu\text{A}$              | 400        | -    | -    | V     |
| Maximum forward voltage                                                      | $V_{FM}$ | $I_F = 160\text{ A}$                        | -          | 1.10 | 1.35 |       |
|                                                                              |          | $I_F = 320\text{ A}$                        | -          | 1.30 | 1.54 |       |
|                                                                              |          | $I_F = 160\text{ A}, T_J = 125\text{ °C}$   | -          | 1.00 | 1.20 |       |
| Maximum reverse leakage current                                              | $I_{RM}$ | $T_J = 125\text{ °C}, V_R = 400\text{ V}$   | See fig. 2 | 0.9  | 3    | mA    |
| Junction capacitance                                                         | $C_T$    | $V_R = 200\text{ V}$                        | See fig. 3 | 370  | 500  | pF    |
| Series inductance                                                            | $L_S$    | From top of terminal hole to mounting plane | -          | 5.0  | -    | nH    |



| DYNAMIC RECOVERY CHARACTERISTICS (T <sub>J</sub> = 25 °C unless otherwise specified) |                          |                                                                               |                                                                                    |      |      |      |       |
|--------------------------------------------------------------------------------------|--------------------------|-------------------------------------------------------------------------------|------------------------------------------------------------------------------------|------|------|------|-------|
| PARAMETER                                                                            | SYMBOL                   | TEST CONDITIONS                                                               |                                                                                    | MIN. | TYP. | MAX. | UNITS |
| Reverse recovery time<br>See fig. 5                                                  | t <sub>rr</sub>          | I <sub>F</sub> = 1.0 A, dI <sub>F</sub> /dt = 200 A/μs, V <sub>R</sub> = 30 V |                                                                                    | -    | 45   | -    | ns    |
|                                                                                      |                          | T <sub>J</sub> = 25 °C                                                        | I <sub>F</sub> = 160 A<br>dI <sub>F</sub> /dt = 200 A/μs<br>V <sub>R</sub> = 200 V | -    | 90   | 140  |       |
|                                                                                      |                          | T <sub>J</sub> = 125 °C                                                       |                                                                                    | -    | 290  | 440  |       |
| Peak recovery current<br>See fig. 6                                                  | I <sub>RRM</sub>         | T <sub>J</sub> = 25 °C                                                        |                                                                                    | -    | 8.7  | 20   | A     |
|                                                                                      |                          | T <sub>J</sub> = 125 °C                                                       |                                                                                    | -    | 18   | 30   |       |
| Reverse recovery charge<br>See fig. 7                                                | Q <sub>rr</sub>          | T <sub>J</sub> = 25 °C                                                        |                                                                                    | -    | 420  | 1100 | nC    |
|                                                                                      |                          | T <sub>J</sub> = 125 °C                                                       |                                                                                    | -    | 2600 | 7000 |       |
| Peak rate of recovery current<br>See fig. 8                                          | dI <sub>(rec)</sub> M/dt | T <sub>J</sub> = 25 °C                                                        |                                                                                    | -    | 300  | -    | A/μs  |
|                                                                                      |                          | T <sub>J</sub> = 125 °C                                                       |                                                                                    | -    | 280  | -    |       |

| THERMAL - MECHANICAL SPECIFICATIONS            |             |                                   |          |      |          |                     |
|------------------------------------------------|-------------|-----------------------------------|----------|------|----------|---------------------|
| PARAMETER                                      |             | SYMBOL                            | MIN.     | TYP. | MAX.     | UNITS               |
| Maximum junction and storage temperature range |             | T <sub>J</sub> , T <sub>Stg</sub> | -55      | -    | 150      | °C                  |
| Thermal resistance, junction to case           | per leg     | R <sub>thJC</sub>                 | -        | -    | 0.19     | °C/W<br>K/W         |
|                                                | per module  |                                   | -        | -    | 0.095    |                     |
| Typical thermal resistance, case to heatsink   |             | R <sub>thCS</sub>                 | -        | 0.10 | -        |                     |
| Weight                                         |             |                                   | -        | 68   | -        | g                   |
|                                                |             |                                   | -        | 2.4  | -        | oz.                 |
| Mounting torque <sup>(1)</sup>                 |             |                                   | 30 (3.4) | -    | 40 (4.6) | N · m<br>(lbf · in) |
|                                                | center hole |                                   | 12 (1.4) | -    | 18 (2.1) |                     |
| Terminal torque                                |             |                                   | 30 (3.4) | -    | 40 (4.6) |                     |
| Vertical pull                                  |             |                                   | -        | -    | 80       | lbf · in            |
| 2" lever pull                                  |             |                                   | -        | -    | 35       |                     |

**Note**

- (1) Mounting surface must be smooth, flat, free of burrs or other protrusions. Apply a thin even film or thermal grease to mounting surface. Gradually tighten each mounting bolt in 5 to 10 lbf · in steps until desired or maximum torque limits are reached.

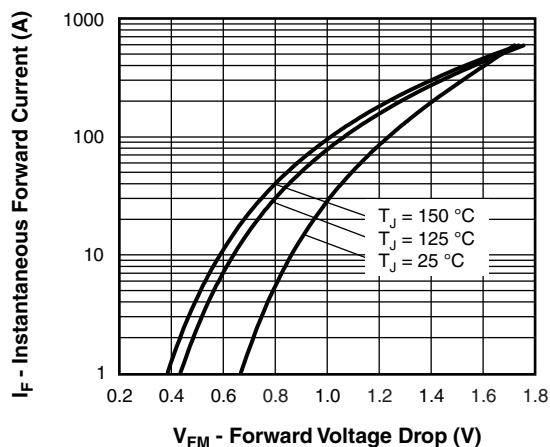


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current (Per Leg)

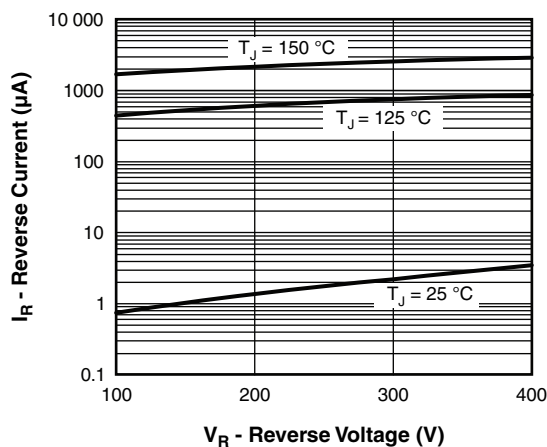


Fig. 2 - Typical Reverse Current vs. Reverse Voltage (Per Leg)

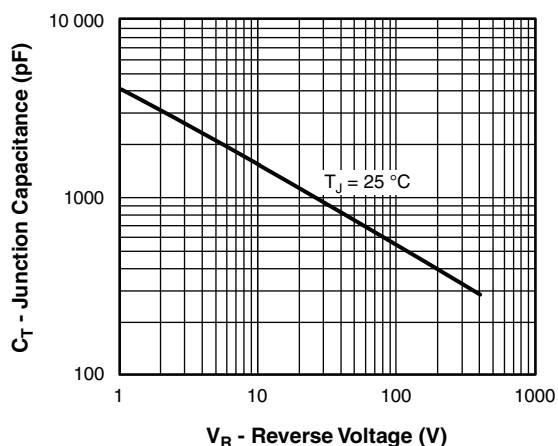


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

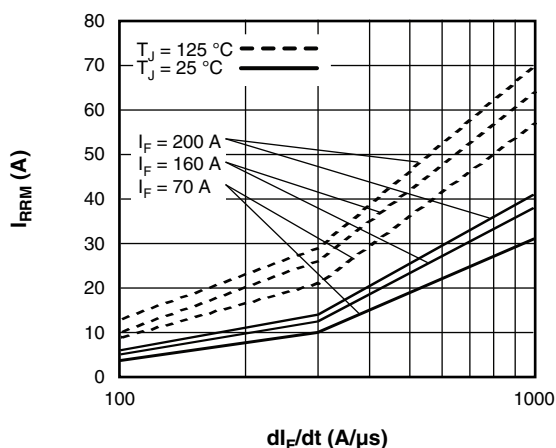


Fig. 6 - Typical Recovery Current vs.  $dI_F/dt$  (Per Leg)

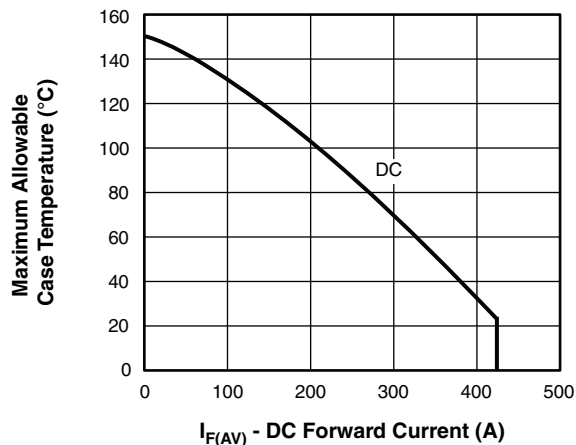


Fig. 4 - Maximum Allowable Case Temperature vs. DC Forward Current (Per Leg)

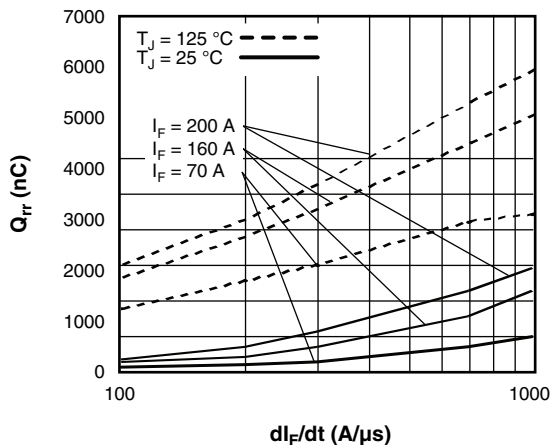


Fig. 7 - Typical Stored Charge vs.  $dI_F/dt$  (Per Leg)

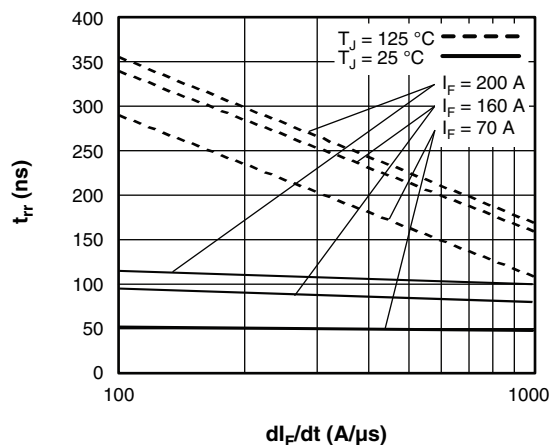


Fig. 5 - Typical Reverse Recovery Time vs.  $dI_F/dt$  (Per Leg)

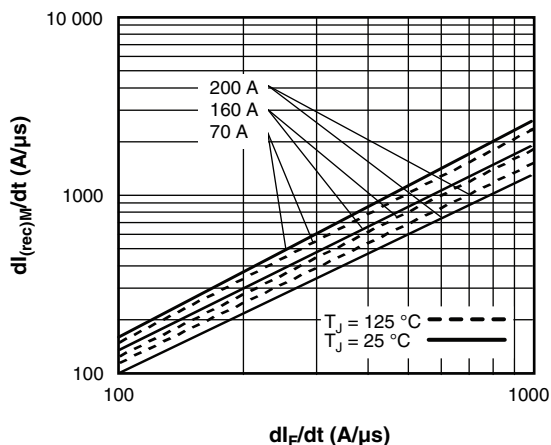


Fig. 8 - Typical  $dI_{(rec)M}/dt$  vs.  $dI_F/dt$  (Per Leg)

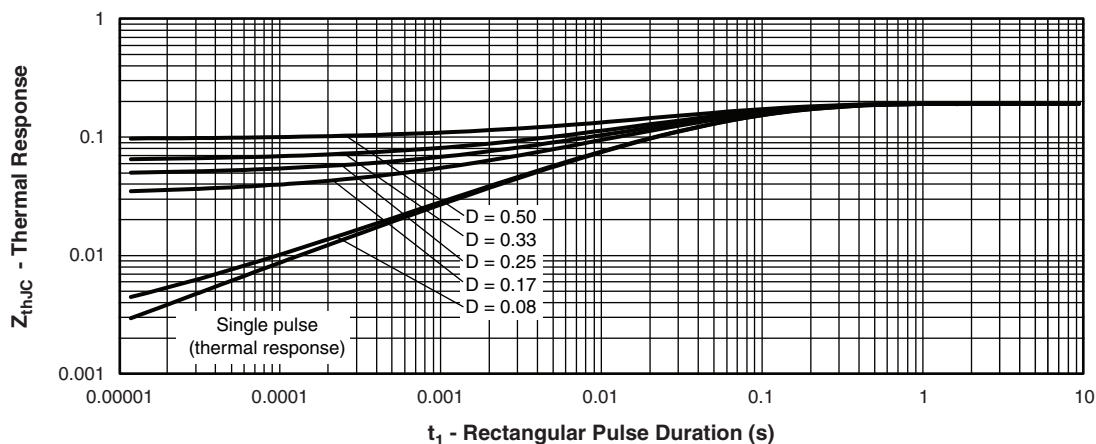


Fig. 9 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics (Per Leg)

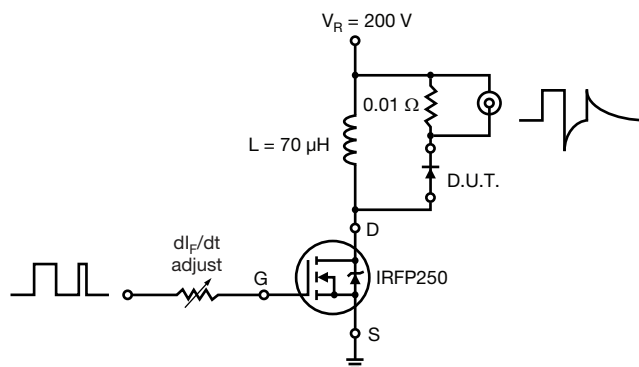


Fig. 10 - Reverse Recovery Parameter Test Circuit

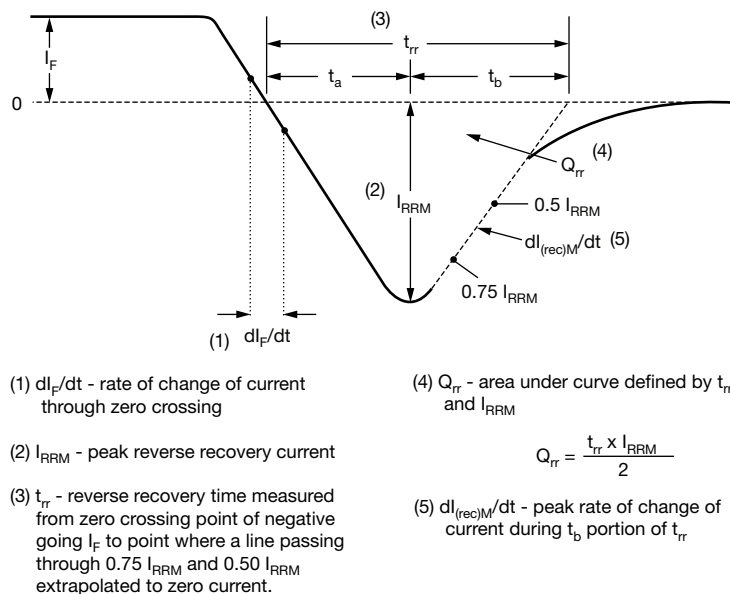


Fig. 11 - Reverse Recovery Waveform and Definitions

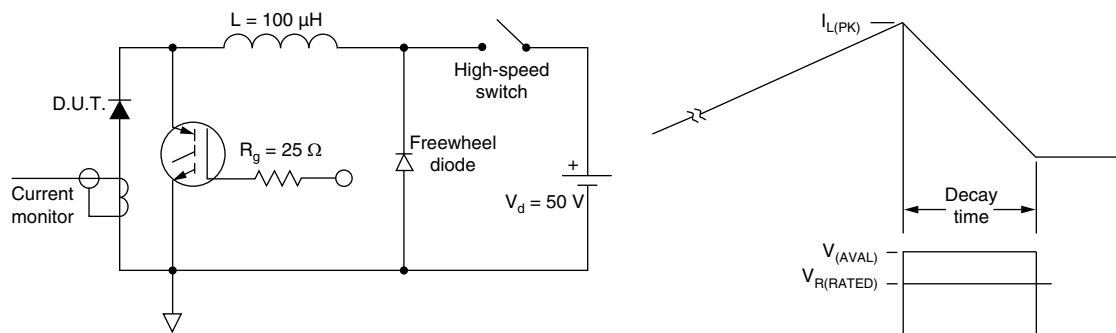


Fig. 12 - Avalanche Test Circuit and Waveforms

## ORDERING INFORMATION TABLE

| Device code | VS- | HFA | 320 | NJ | 40 | C | PbF |
|-------------|-----|-----|-----|----|----|---|-----|
|             | 1   | 2   | 3   | 4  | 5  | 6 | 7   |
|             | 1   | 2   | 3   | 4  | 5  | 6 | 7   |
|             | 1   | 2   | 3   | 4  | 5  | 6 | 7   |
|             | 1   | 2   | 3   | 4  | 5  | 6 | 7   |
|             | 1   | 2   | 3   | 4  | 5  | 6 | 7   |
|             | 1   | 2   | 3   | 4  | 5  | 6 | 7   |

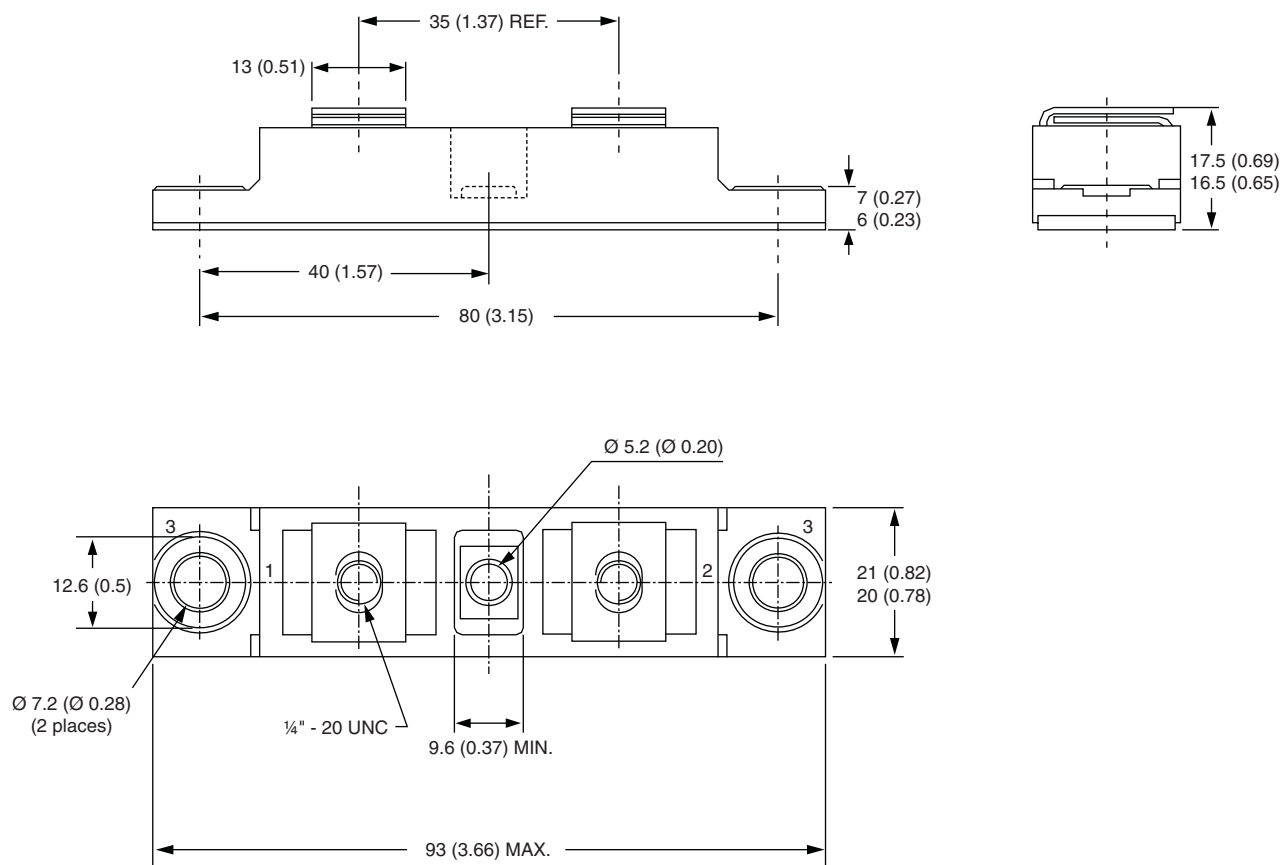
- 1 - Vishay Semiconductors product
- 2 - HEXFRED® family, electron irradiated
- 3 - Average current rating
- 4 - NJ = TO-244
- 5 - Voltage rating (400 V)
- 6 - C = Common cathode
- 7 - Lead (Pb)-free

| LINKS TO RELATED DOCUMENTS |                                                                        |
|----------------------------|------------------------------------------------------------------------|
| Dimensions                 | <a href="http://www.vishay.com/doc?95021">www.vishay.com/doc?95021</a> |



## TO-244

**DIMENSIONS** in millimeters (inches)





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**Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.**

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